

P-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY

| V_{DS} (V) | $R_{DS(on)}$ (Ω) | I_D (A) |
|--------------|-----------------------------|-----------|
| - 30 | 0.053 at $V_{GS} = - 10$ V | - 4.0 |
| | 0.086 at $V_{GS} = - 4.5$ V | - 3.1 |

FEATURES

- Halogen-free According to IEC 61249-2-21 Available
- TrenchFET® Power MOSFET

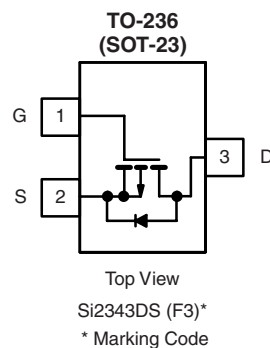


RoHS*
COMPLIANT

HALOGEN
FREE
Available

APPLICATIONS

- Load Switch
- PA Switch



Ordering Information: Si2343DS-T1
Si2343DS-T1-E3 (Lead (Pb)-free)
Si2343DS-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS $T_A = 25$ °C, unless otherwise noted

| Parameter | Symbol | 5 s | Steady State | Unit |
|--|----------------|-------------|--------------|------|
| Drain-Source Voltage | V_{DS} | - 30 | | V |
| Gate-Source Voltage | V_{GS} | ± 20 | | |
| Continuous Drain Current ($T_J = 150$ °C) ^{a, b} | I_D | - 4.0 | - 3.1 | A |
| | | - 3.2 | - 2.5 | |
| Pulsed Drain Current | I_{DM} | - 15 | | |
| Continuous Source Current (Diode Conduction) ^{a, b} | I_S | - 1.0 | - 0.6 | W |
| Maximum Power Dissipation ^{a, b} | P_D | 1.25 | 0.75 | |
| | | 0.8 | 0.48 | |
| Operating Junction and Storage Temperature Range | T_J, T_{stg} | - 55 to 150 | | °C |

THERMAL RESISTANCE RATINGS

| Parameter | Symbol | Typical | Maximum | Unit |
|--|------------|---------|---------|------|
| Maximum Junction-to-Ambient ^a | R_{thJA} | 75 | 100 | °C/W |
| | | 120 | 166 | |
| Maximum Junction-to-Foot (Drain) | R_{thJF} | 40 | 50 | |

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

b. Pulse width limited by maximum junction temperature.

* Pb containing terminations are not RoHS compliant, exemptions may apply

| SPECIFICATIONS T _J = 25 °C, unless otherwise noted | | | | | | |
|---|----------------------|--|--------|-------|-------|------|
| Parameter | Symbol | Test Conditions | Limits | | | Unit |
| | | | Min. | Typ. | Max. | |
| Static | | | | | | |
| Drain-Source Breakdown Voltage | V _{(BR)DSS} | V _{GS} = 0 V, I _D = - 250 μA | - 30 | | | V |
| Gate-Threshold Voltage | V _{GS(th)} | V _{DS} = V _{GS} , I _D = - 250 μA | - 1 | | - 3 | |
| Gate-Body Leakage | I _{GSS} | V _{DS} = 0 V, V _{GS} = ± 20 V | | | ± 100 | nA |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} = - 24 V, V _{GS} = 0 V | | | - 1 | μA |
| | | V _{DS} = - 24 V, V _{GS} = 0 V, T _J = 55 °C | | | - 10 | |
| On-State Drain Current ^a | I _{D(on)} | V _{DS} ≤ - 5 V, V _{GS} = - 10 V | - 15 | | | A |
| Drain-Source On-Resistance ^a | R _{DS(on)} | V _{GS} = - 10 V, I _D = - 4.0 A | | 0.043 | 0.053 | Ω |
| | | V _{GS} = - 4.5 V, I _D = - 3.1 A | | 0.068 | 0.086 | |
| Forward Transconductance ^a | g _{fs} | V _{DS} = - 5 V, I _D = - 4.0 A | | 10 | | S |
| Diode Forward Voltage | V _{SD} | I _S = - 1.0 A, V _{GS} = 0 V | | - 0.7 | - 1.2 | V |
| Dynamic ^b | | | | | | |
| Total Gate Charge | Q _g | V _{DS} = - 15 V, V _{GS} = - 10 V I _D ≅ - 4.0 A | | 14 | 21 | nC |
| Gate-Source Charge | Q _{gs} | | | 1.9 | | |
| Gate-Drain Charge | Q _{gd} | | | 3.7 | | |
| Input Capacitance | C _{iss} | V _{DS} = - 15 V, V _{GS} = 0 V, f = 1 MHz | | 540 | | pF |
| Output Capacitance | C _{oss} | | | 131 | | |
| Reverse Transfer Capacitance | C _{rss} | | | 105 | | |
| Switching ^c | | | | | | |
| Turn-On Time | t _{d(on)} | V _{DD} = - 15 V, R _L = 15 Ω I _D ≅ - 1.0 A, V _{GEN} = - 10 V R _G = 6 Ω | | 10 | 15 | ns |
| | t _r | | | 15 | 25 | |
| Turn-Off Time | t _{d(off)} | | | 31 | 50 | |
| | t _f | | | 20 | 30 | |

Notes:

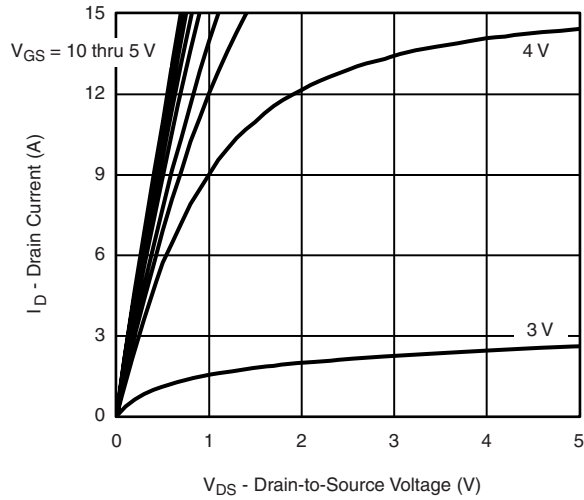
a. Pulse test: $PW \leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$.

b. For DESIGN AID ONLY, not subject to production testing.

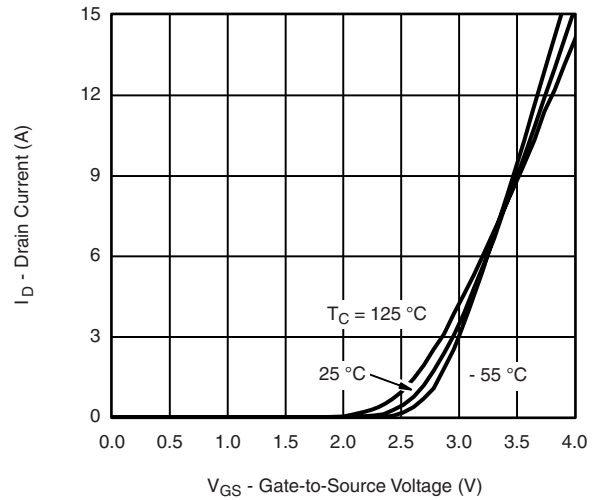
c. Switching time is essentially independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

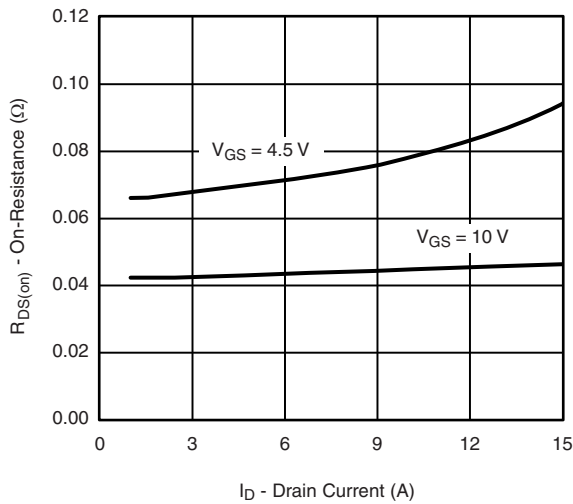
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



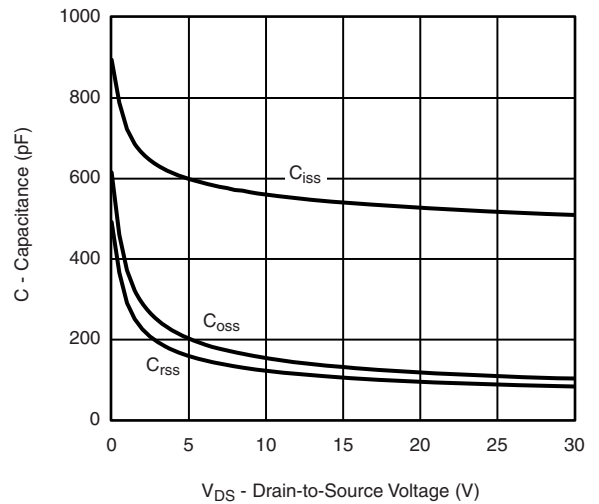
Output Characteristics



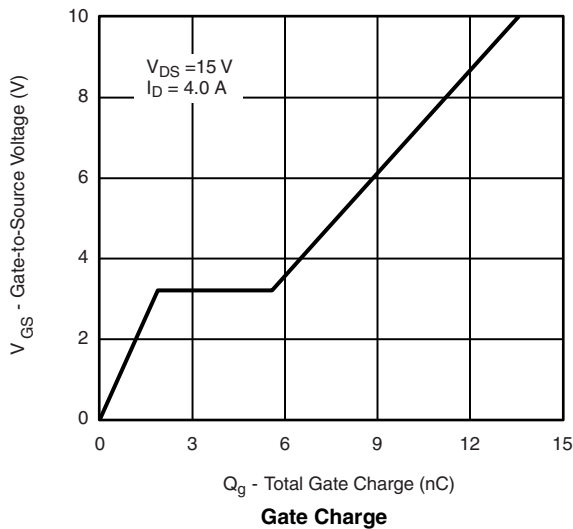
Transfer Characteristics



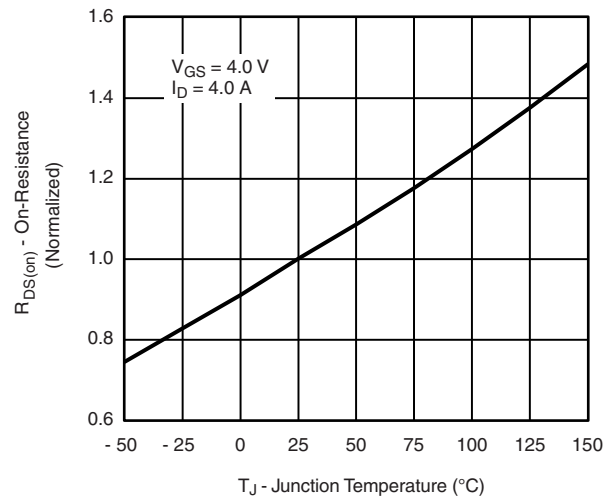
On-Resistance vs. Drain Current



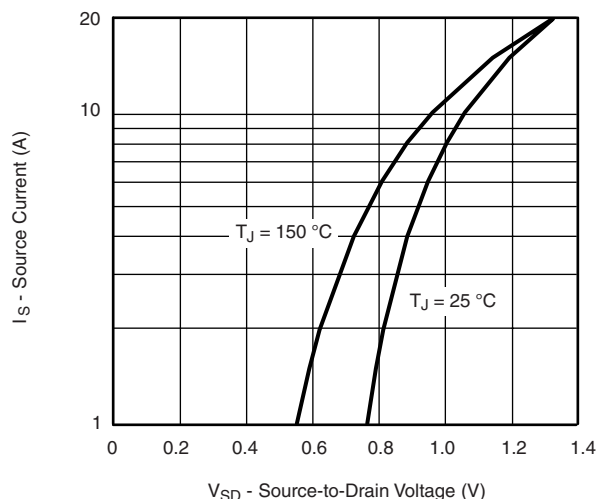
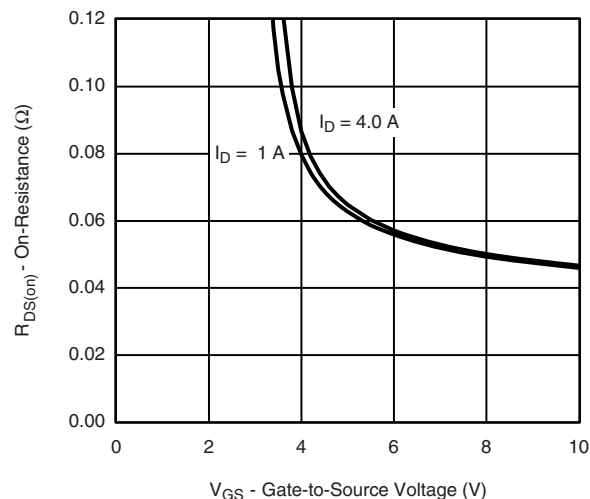
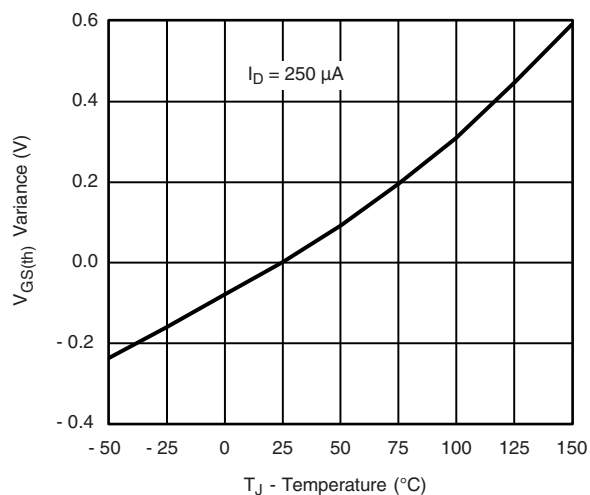
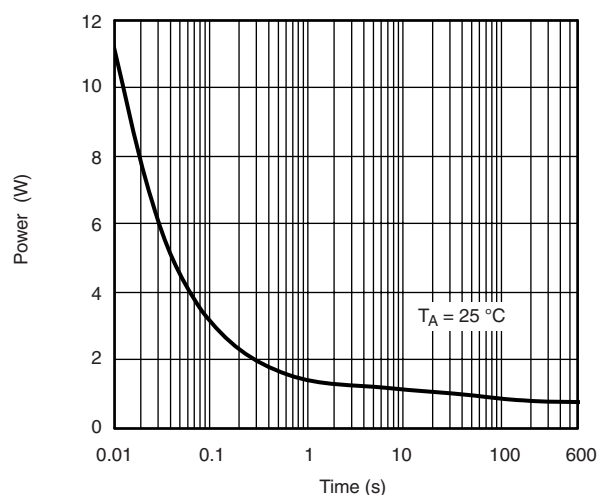
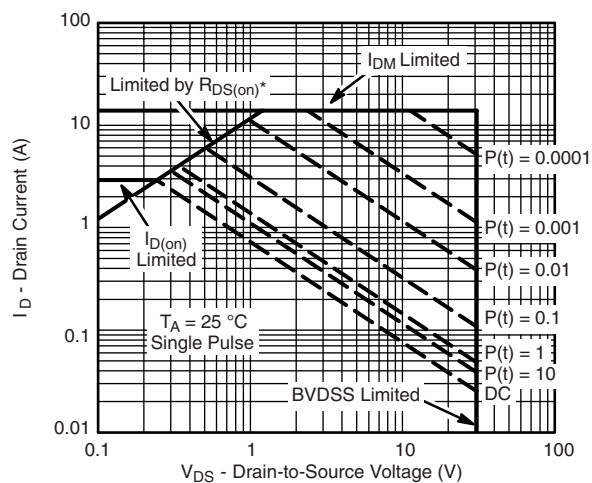
Capacitance



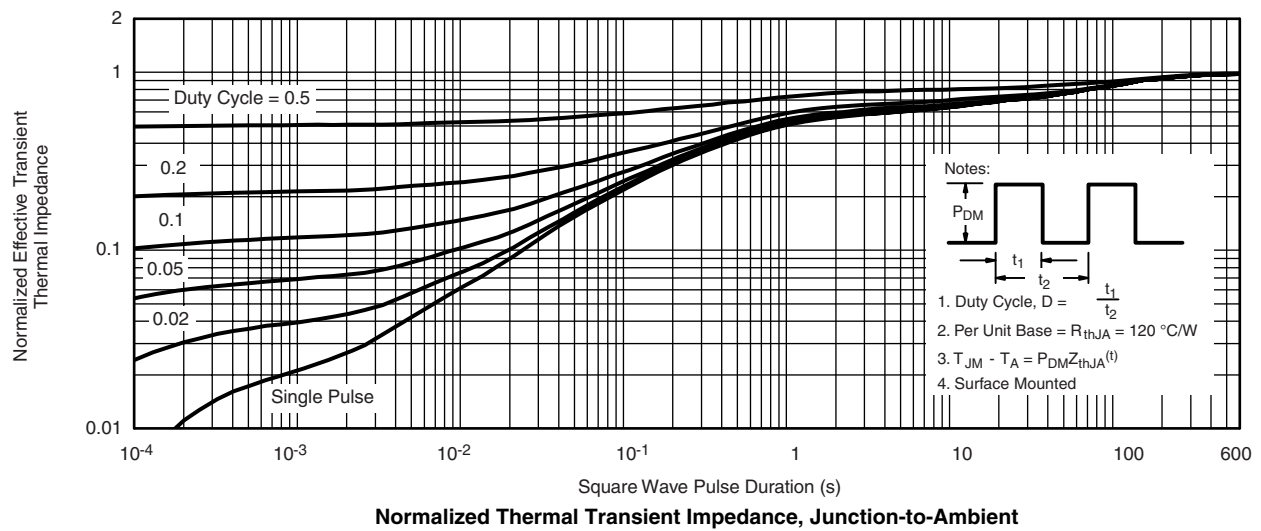
Gate Charge



On-Resistance vs. Junction Temperature

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted**Source-Drain Diode Forward Voltage****On-Resistance vs. Gate-to-Source Voltage****Threshold Voltage****Single Pulse Power*** $V_{GS} >$ minimum V_{GS} at which $R_{DS(on)}$ is specified**Safe Operating Area**

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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SOT-23 (TO-236): 3-LEAD



| Dim | MILLIMETERS | | INCHES | |
|--------------------------------|-------------|------|------------|-------|
| | Min | Max | Min | Max |
| A | 0.89 | 1.12 | 0.035 | 0.044 |
| A ₁ | 0.01 | 0.10 | 0.0004 | 0.004 |
| A ₂ | 0.88 | 1.02 | 0.0346 | 0.040 |
| b | 0.35 | 0.50 | 0.014 | 0.020 |
| c | 0.085 | 0.18 | 0.003 | 0.007 |
| D | 2.80 | 3.04 | 0.110 | 0.120 |
| E | 2.10 | 2.64 | 0.083 | 0.104 |
| E ₁ | 1.20 | 1.40 | 0.047 | 0.055 |
| e | 0.95 BSC | | 0.0374 Ref | |
| e ₁ | 1.90 BSC | | 0.0748 Ref | |
| L | 0.40 | 0.60 | 0.016 | 0.024 |
| L ₁ | 0.64 Ref | | 0.025 Ref | |
| S | 0.50 Ref | | 0.020 Ref | |
| q | 3° | 8° | 3° | 8° |
| ECN: S-03946-Rev. K, 09-Jul-01 | | | | |
| DWG: 5479 | | | | |

RECOMMENDED MINIMUM PADS FOR SOT-23



Recommended Minimum Pads
Dimensions in Inches/(mm)

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